



Atty. Dkt. No. PAT004 US ^{PATENT}

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:
Wen-Yen Hwang
Serial No.: 09/820,072
Confirmation No.: 4037
Filed: March 28, 2001
For: Alternative Substrates for
Epitaxial Growth

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Group Art Unit: 2815
Examiner: Joseph H. Nguyen
Atty. Docket No.: PAT004US

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Amend a
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BOX NON-FEE AMENDMENT
Commissioner for Patents
Washington, D.C. 20231

**CERTIFICATE OF MAILING BY FIRST CLASS MAIL
DATE OF DEPOSIT: December 31, 2002**

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail on the date indicated above and is addressed to Assistant Commissioner for Patents, Box Non-Fee Amendment, Washington, D.C. 20231-0001.

N. H. Kinella
N. STEPHAN KINSELLA

RESPONSE TO OFFICE ACTION DATED 10/08/2002

Dear Sir:

The following amendments and remarks are respectfully submitted in response to the non-final Office Action dated 10/08/2002.

AMENDMENTS

Amend the present application as follows:

IN THE SPECIFICATION

On page 3, replace the paragraph spanning lines 21-24 with the following rewritten paragraph:

--It is desirable to epitaxially fabricate a variety of types of structures or devices, using a given epi material system, grown on a given substrate. Such epitaxially fabricated devices include electronic devices, such as transistors and integrated circuits, and optoelectronic devices, such as semiconductor lasers, light-emitting diodes, and photodetectors.--

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